



## CR03AM-16 1.25A Sensitive SCR

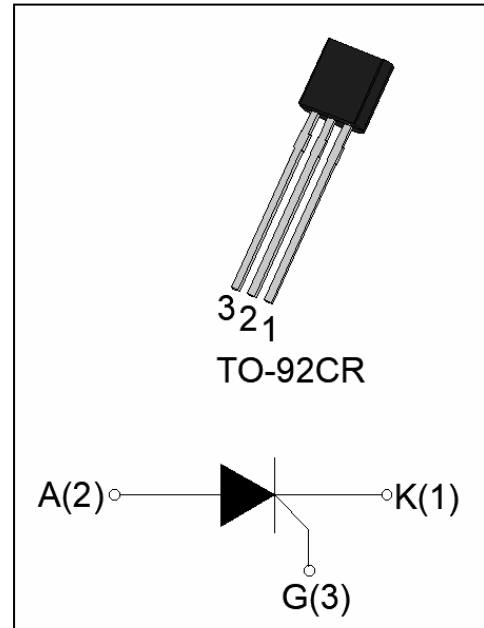
Rev.A.2.2

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The CR03AM-16 SCR provides high dV/dt rate with strong resistance to electromagnetic interface. It is especially recommended for use on residual current circuit breaker, straight hair, igniter etc. Package TO-92CR is RoHS compliant.

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Symbol	Value	Unit
$I_{T(RMS)}$	1.25	A
$V_{DRM} / V_{RRM}$	1250	V
$I_{GT}$	200	$\mu A$



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Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-110	
Repetitive peak off-state voltage ( $T_j=25^\circ C$ )	$V_{DRM}$	1250	V
Repetitive peak reverse voltage ( $T_j=25^\circ C$ )	$V_{RRM}$	1250	V
Average on-state current ( $T_c=42^\circ C$ )	$I_{T(AV)}$	0.8	A
RMS on-state current ( $T_c=42^\circ C$ )	$I_{T(RMS)}$	1.25	A
Non repetitive surge peak on-state current ( $t_p=10ms, T_j=25^\circ C$ )	$I_{TSM}$	25	A
Non repetitive surge peak on-state current ( $t_p=8.3ms, T_j=25^\circ C$ )		28	
$I^2t$ value for fusing ( $t_p=10ms, T_j=25^\circ C$ )	$I^2t$	3.1	$A^2s$
Critical rate of rise of on-state current ( $I_G=2 I_{GT}, f=100Hz, T_j=110^\circ C$ )	$di/dt$	100	$A/\mu s$
Peak gate current ( $t_p=20\mu s, T_j=110^\circ C$ )	$I_{GM}$	1.2	A
Average gate power dissipation ( $T_j=110^\circ C$ )	$P_{G(AV)}$	0.2	W

Peak gate power	$P_{GM}$	2	W
Peak pulse voltage ( $T_j=25^\circ\text{C}$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	1	kV

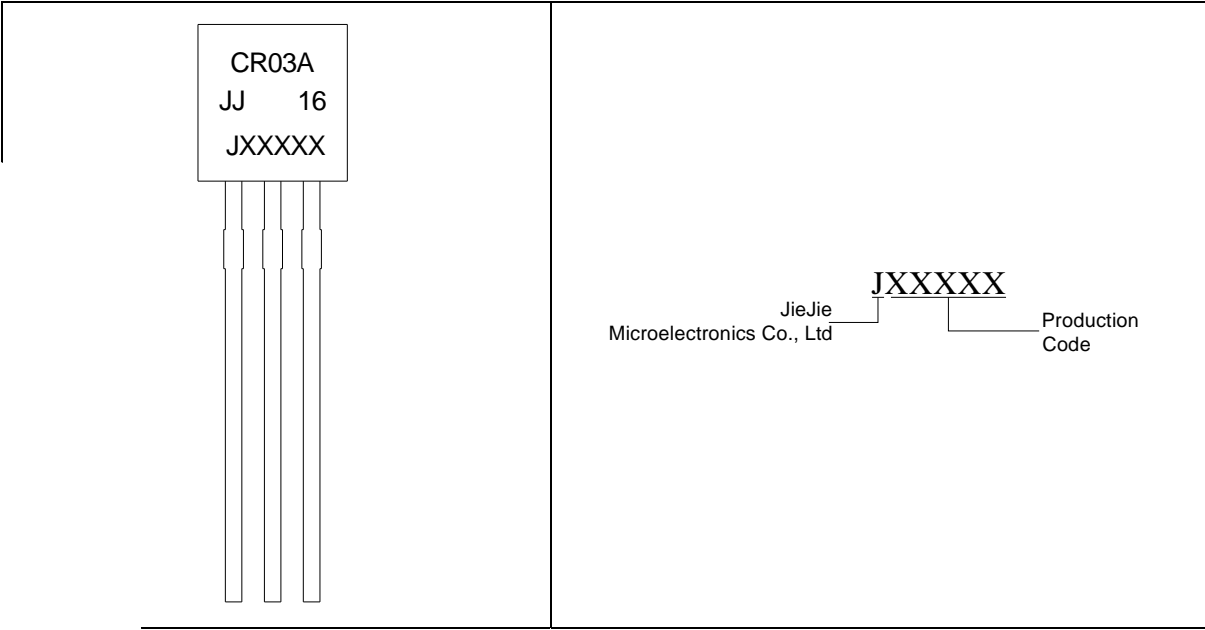
>  $dZ/dt$  ,  $Z$  d  $Z/dt$  / unless otherwise specified )

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
$I_{GT}$	$V_D=12V R_L=33$	-	50	200	$\mu\text{A}$
$V_{GT}$		-	0.6	0.8	V
$V_{GD}$	$V_D=V_{DRM} T_j=110$	0.2	-	-	V
$I_L$	$I_G=1.2 I_{GT}$	-	-	5	mA
$I_H$	$I_T=0.05A$	-	-	4	mA
$dV/dt$	$V_D=800V T_j=110 R_{GK}=1k$	200	-	-	$V/\mu\text{s}$
	$V_D=800V T_j=110 R_{GK}=220$	1000	-	-	
$t_{on}$	$I_G=10mA I_A=20mA I_R=2mA$	-	2	-	$\mu\text{s}$
$t_{off}$	$T_j=25$	-	50	-	$\mu\text{s}$

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Symbol	Parameter	Value(MAX.)	Unit
$V_{TM}$	$I_T=2A t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	$v \in \text{D} M3P \in 1 .3$ s_ V

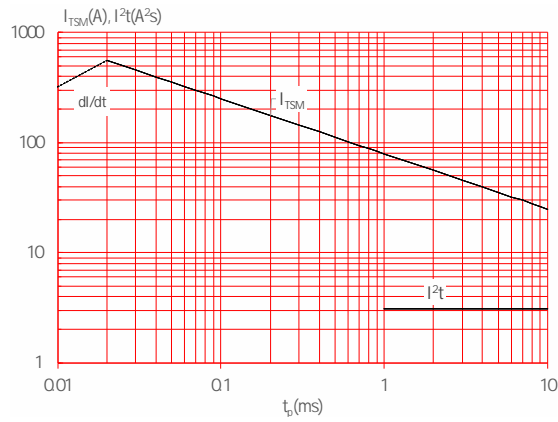
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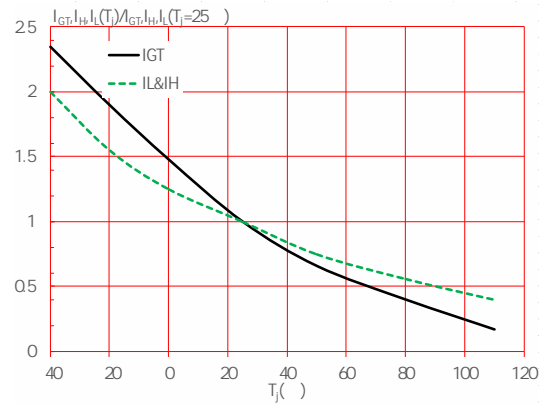
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**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$  ( $di/dt < 100\text{A}/\mu\text{s}$ )

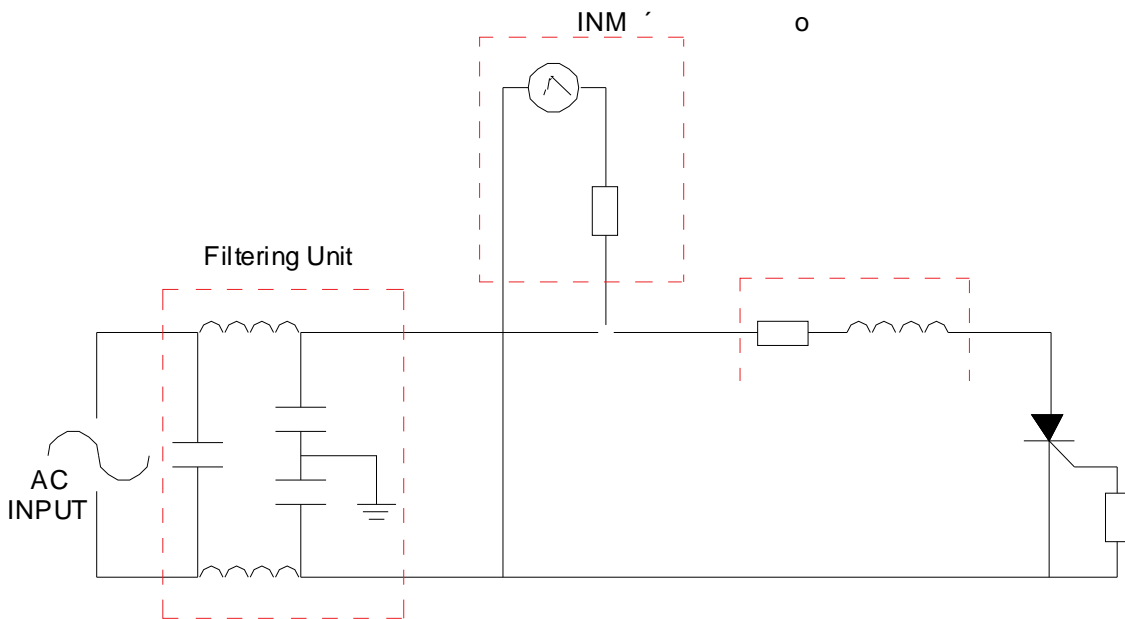


**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



**FIG.7** ÖTest circuit for inductive and resistive loads to IEC-61000-4-5 standards.

IEC61000-4-5 Standards  
Surge Generator



KZ Z/E' /E &amp; KZD d/KE

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT( $\mu$ A)	Package	Base qty. (pcs)	Delivery mode
CR03AM-16	1250	200	TO-92CR	1,000	Bulk Pack
CR03AM-16-TR				2,000	Tape & Reel

**CR03AM-16**

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